

RD151TS3313ARP, RD151TS3323ARP

Spread Spectrum Clock for EMI Solution

REJ03D0794-0100 Rev.1.00 May 11, 2006

Description

RD151TS3313ARP and RD151TS3323ARP is a high-performance Spread Spectrum Clock generator. It is suitable for EMI solution of electric systems.

Features

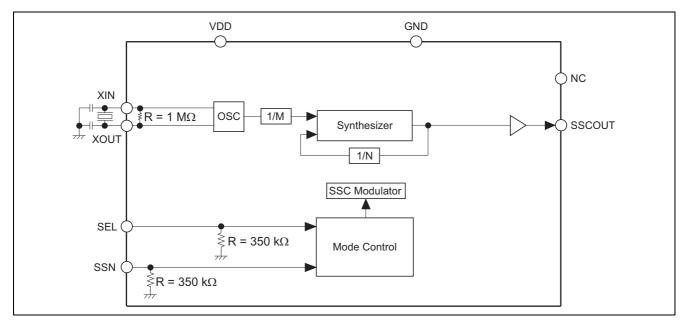
- Supports 20 MHz to 40 MHz operations. Multiple rate (XIN: SSCOUT) = 1: 1 Input frequency 20 MHz to 40 MHz
- Spread spectrum modulation; RD151TS3313ARP: ±1.5%, ±0.5% (Central spread modulation) RD151TS3323ARP: -3.0%, -1.0% (Down spread modulation)

Key Specifications

- Supply voltages: $V_{DD} = 3.3 \text{ V} \pm 0.3 \text{ V}$
- Cycle to cycle jitter = ± 100 ps typ.
- Clock output duty cycle = $50 \pm 5\%$
- Output slew rate = 0.7 V/ns typ.
- Ordering Information

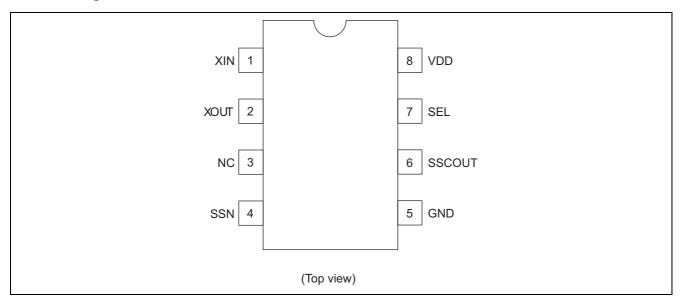
Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
RD151TS3313ARPH0	SOP-8 pin	PRSP0008DD-C	RP	H (2,500 pcs / Reel)
RD151TS3323ARPH0	(JEDEC)	(FP-8DCV)		

Block Diagram





Pin Arrangement



Pin Descriptions

Pin name	No.	Туре	Description
GND	5	Ground	GND pin
VDD	8	Power	Power supply pin.
NC	3	NC	Don't connect any VDD or GND.
SSCOUT	6	Output	Spread spectrum modulated clock output.
XIN	1	Input	Oscillator input.
XOUT	2	Output	Oscillator output.
SEL	7	Input	SSC% mode select pin. LVCMOS level input. Pull-down by internal resistor (350 k Ω).
SSN	4	Input	SSC ON/OFF select pin. LVCMOS level input. Pull-down by internal resistor (350 k Ω).

SSC Function Table

STB	SEL	RD151TS3313ARP(Central spread)	RD151TS3323ARP(Down spread)
0	0	±1.5%* ¹	-3.0%* ¹
0	1	±0.5%	-1.0%
1	0	OFF	OFF
1	1	OFF	OFF

Note: 1. ±1.5% (TS3313ARP) / -3.0% (TS3323ARP) SSC is selected for default by internal pull-down resistors.

Clock Frequency Table

PRODUCT	XIN(MHz)	SSCOUT(MHz)	Multiply rate (XIN: SSCOUT)
RD151TS3313ARP	20 to 40	20 to 40	1:1
RD151TS3323ARP	20 to 40	20 to 40	1:1



Absolute Maximum Ratings

ltem	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{DD}	-0.5 to 4.6	V	
Input voltage	VI	-0.5 to 4.6	V	
Output voltage ^{*1}	Vo	–0.5 to V _{DD} +0.5	V	
Input clamp current	I _{IK}	-50	mA	V ₁ < 0
Output clamp current	Ι _{ΟΚ}	-50	mA	V ₀ < 0
Continuous output current	Ι _Ο	±50	mA	$V_{O} = 0$ to V_{DD}
Maximum power dissipation		0.7	W	Ta = 55°C (in still air)
Storage temperature	T _{stg}	-65 to +150	°C	

Notes: Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device.

1. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

Recommended Operating Conditions

ltem	Symbol	Min	Тур	Max	Unit	Conditions
Supply voltage	V _{DD}	3.0	3.3	3.6	V	
DC input signal voltage		-0.3	_	V _{DD} +0.3	V	
High level input voltage	V _{IH}	0.7×V _{DD}	_	V _{DD} +0.3	V	
Low level input voltage	VIL	-0.3	_	0.3×V _{DD}	V	
Input clock duty cycle		45	50	55	%	
Operating temperature	Ta	-20		85	°C	

DC Electrical Characteristics

Ta = -20 to 85 °C, V_{DD} = 3.0 to 3.6 V

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input current	lı –	_		±20	μΑ	$V_1 = 0 V \text{ or } 3.6 V, V_{DD} = 3.6 V,$
						XIN pin
		_	_	±100		$V_1 = 0 V \text{ or } 3.6 V, V_{DD} = 3.6 V,$
						SEL, SSN pins
Input capacitance	Cı		3	—	pF	SEL, SSN pins

DC Electrical Characteristics / SSC Clock Output

Ta = -20 to 85 °C, V_{DD} = 3.0 to 3.6 V

ltem	Symbol	Min	Тур	Max	Unit	Test Conditions
Output voltage	V _{OH}	V _{DD} -0.2		—	V	$I_{OH} = -1 \text{ mA}$
	V _{OL}	_	-	200	mV	I _{OL} = 1 mA
Output current	I _{ОН}	_	-13	—	mA	V _{OH} = 1.5 V, V _{DD} = 3.3 V
	I _{OL}	_	13	—		V _{OL} = 1.5 V, V _{DD} = 3.3 V
Output impedance			40	_	Ω	

Note: Parameters are target of design. Not 100% tested in production.

AC Electrical Characteristics / SSC Clock Output

						$Ta = 25^{\circ}C, V_{DD} = 3.3$	$V, C_L = 15 p$
ltem	Symbol	Min	Тур	Max	Unit	Test Conditions	Notes
Operating current	I _{DD}	_	14	19	mA	$V_{\text{DD}} = 3.3 \text{ V}, \text{ C}_{\text{L}} = 15 \text{ pF},$ $\text{XIN} = 40 \text{ MHz}$	
Cycle to cycle jitter * ¹	tccs	_	100	—	ps	SEL = 0, C _L = 0 pF SSC = ±1.5% (TS3313ARP) SSC = -3.0% (TS3323ARP)	Figure 1
Slew rate	t _{SL}	_	0.7	4.0	V/ns	$V_{DD} = 3.3 \text{ V},$ 0.2 × V_{DD} to 0.8 × V_{DD}	
Clock duty cycle		45	50	55	%		
Stabilization time ^{*2}		_	_	2	ms		

Notes: Parameters are target of design. Not 100% tested in production.

1. Cycle to cycle jitter is included spread spectrum modulation.

2. Stabilization time is the time required for the integrated circuit to obtain phase lock of its input signal after power up.

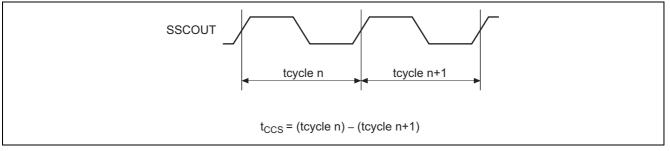


Figure 1 Cycle to cycle jitter



Application Information

1. Recommended Circuit Configuration

The power supply circuit of the optimal performance on the application of a system should refer to Figure 2.

VDD decoupling is important to both reduce Jitter and EMI radiation.

The C1 decoupling capacitor should be placed as close to the VDD pin as possible, otherwise the increased trace inductance will negate its decoupling capability.

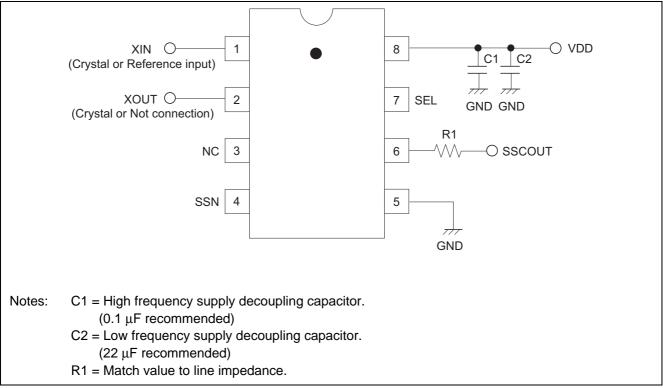
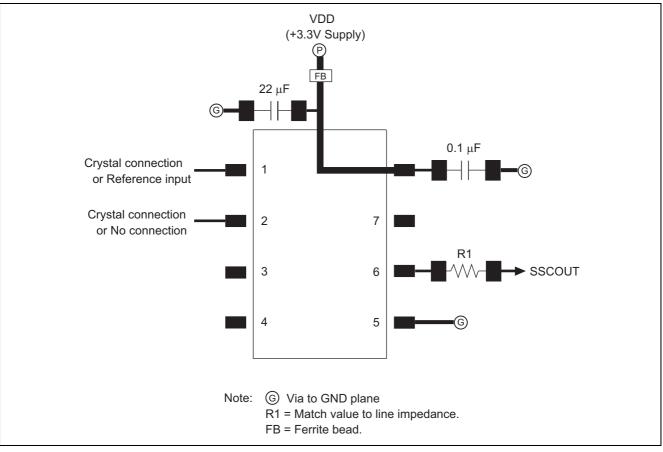


Figure 2 Recommended circuit configuration



2. Example Board Layout Configuration







3. Example of TS33XX EMI Solution IC's Application

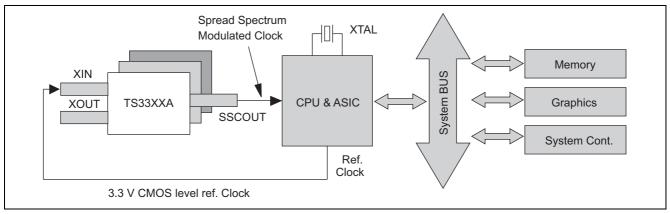


Figure 4 Ref. Clock Input Example

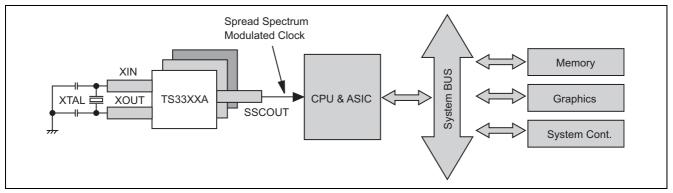
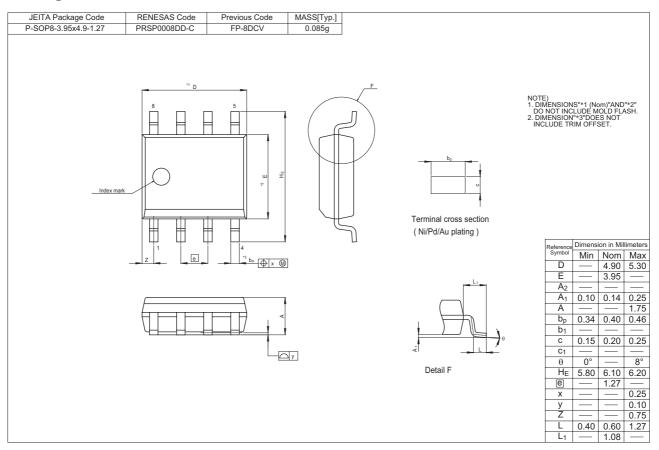


Figure 5 XTAL Ref. Clock Input Example



Package Dimensions





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